

# Stanford

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Ph.D. Student in Applied Physics, admitted Autumn 2018

### Publications

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#### PUBLICATIONS

- **Intertwined States at Finite Temperatures in the Hubbard Model** *JOURNAL OF THE PHYSICAL SOCIETY OF JAPAN*  
Huang, E. W., Wang, W. O., Ding, J. K., Liu, T., Liu, F., Huang, X., Moritz, B., Devereaux, T. P.  
2021; 90 (11)
- **Numerical approaches for calculating the low-field dc Hall coefficient of the doped Hubbard model** *PHYSICAL REVIEW RESEARCH*  
Wang, W. O., Ding, J. K., Moritz, B., Schattner, Y., Huang, E. W., Devereaux, T. P.  
2021; 3 (3)
- **DC Hall coefficient of the strongly correlated Hubbard model** *NPJ QUANTUM MATERIALS*  
Wang, W. O., Ding, J. K., Moritz, B., Huang, E. W., Devereaux, T. P.  
2020; 5 (1)